HS-C²MOS™ INTEGRATED CIRCUITS

0-11946

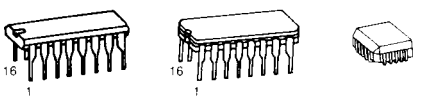
M54HC109
M74HC109

PRELIMINARY DATA

DUAL J-K FLIP FLOP WITH PRESET AND CLEAR

DESCRIPTION

The M54/74HC109 is a high speed CMOS DUAL J-K FLIP FLOP WITH PRESET AND CLEAR fabricated in silicon gate C²MOS technology.
It has the same high speed performance of LSTTL combined with true CMOS low power consumption.
In accordance with the logic level on the J and $\overline{K}$ input this device changes state on positive going transitions of the clock pulse. CLEAR and PRESET are independent of the clock and accomplished by a low logic level on the corrisponding input.
All inputs are equipped with protection circuits against static discharge or trasient excess voltage.



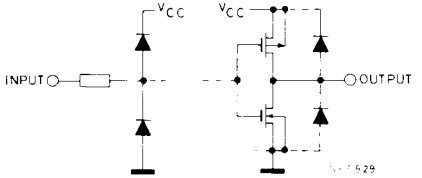
B1 Plastic Package | **F1** Ceramic Package | **C1** Chip Carrier

ORDERING NUMBERS: M54HC109 F1
M74HC109 B1
M74HC109 F1
M74HC109 C1

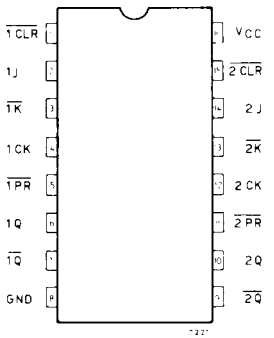
FEATURES

- High Speed
  f_{MAX} = 60 MHz (Typ) at V_{CC} = 5V
- Low Power Dissipation
  I_{CC} = 2 μA (Max.) at T_A = 25°C
- High Noise Immunity
  $V_{NIH} = V_{NIL}$ = 28% V_{CC} (Min.)
- Output Drive Capability
  10 LSTTL Loads
- Symmetrical Output Impedance
  $|I_{OH}| = I_{OL}$ = 4 mA (Min.)
- Balanced Propagation Delays
  $t_{PLH} = t_{PHL}$
- Wide Operating Voltage Range
  V_{CC} (opr) = 2V to 6V
- Pin and Function compatible with 54/74LS109

INPUT AND OUTPUT EQUIVALENT CIRCUIT

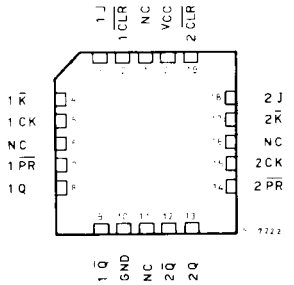


PIN CONNECTIONS
(top view)



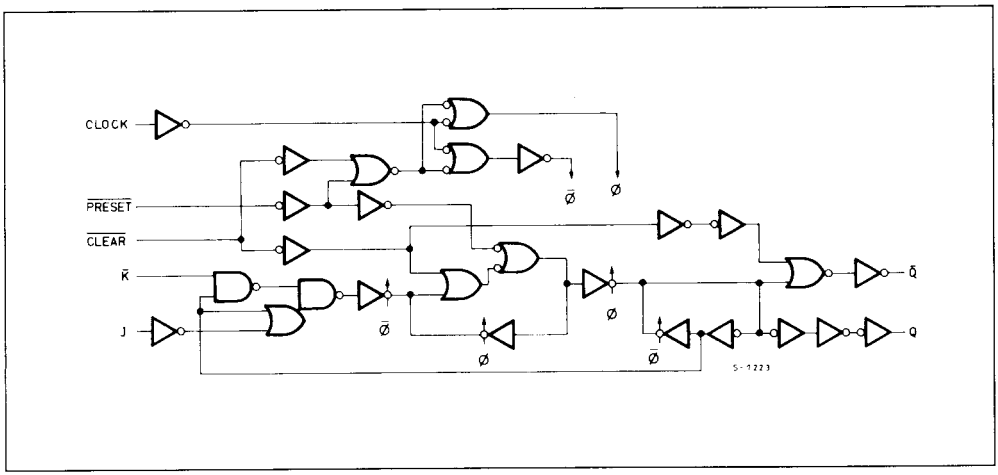
Dual in line

CHIP CARRIER



NC = No Internal Connection

LOGIC DIAGRAM (1/2 Package)



TRUTH TABLE

INPUTS					OUTPUTS		FUNCTION
$\overline{CLR}$	$\overline{PR}$	J	$\overline{K}$	CK	Q	$\overline{Q}$	
L	H	X	X	X	L	H	CLEAR
H	L	X	X	X	H	L	PRESET
L	L	X	X	X	H	H	
H	H	L	H	↓	Qn	$\overline{Q}$n	NO CHANGE
H	H	L	L	↓	L	H	
H	H	H	H	↓	H	L	
H	H	H	L	↓	$\overline{Q}$n	Qn	TOOGLE
H	H	X	X	↓	Qn	$\overline{Q}$n	NO CHANGE

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Limit		Unit
V_{CC}	Supply Voltage		2 to 6		V
V_I	Input Voltage		0 to V_{CC}		V
V_O	Output Voltage		0 to V_{CC}		V
T_A	Operating Temperature	74HC Series 54HC Series	– 40 to 85 – 55 to 125		°C
t_r, t_f	Input Rise and Fall Time	V_{CC} 2 V V_{CC} 4.5V V_{CC} 6 V	0 to 1000 0 to 500 0 to 400		ns

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	−0.5 to 7	V
V_I	DC Input Voltage	−0.5 to V_{CC} + 0.5	V
V_O	DC Output Voltage	−0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Source Sink Current Per Output Pin	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500 (*)	mW
T_{stg}	Storage Temperature	−65 to 150	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW: ≅ 65°C derate to 300 mW by 10 mW/°C: 65°C to 85°C.

DC SPECIFICATIONS

Symbol	Parameter	V_{CC}	Test Condition		T_A = 25°C 54HC and 74HC			−40 to 85°C 74HC		−55 to 125°C 54HC		Unit
					Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.0			1.5	—	—	1.5	—	1.5	—	V
		4.5			3.15	—	—	3.15	—	3.15	—	
		6.0			4.2	—	—	4.2	—	4.2	—	
V_{IL}	Low Level Input Voltage	2.0			—	—	0.5	—	0.5	—	0.5	V
		4.5			—	—	1.35	—	1.35	—	1.35	
		6.0			—	—	1.8	—	1.8	—	1.8	
V_{OH}	High Level Output Voltage	2.0	V_I	I_O	1.9	2.0	—	1.9	—	1.9	—	V
		4.5	V_{IH} or V_{IL}	−20 μA	4.4	4.5	—	4.4	—	4.4	—	
		6.0			5.9	6.0	—	5.9	—	5.9	—	
		4.5		−4.0 mA	4.18	4.31	—	4.13	—	4.10	—	
		6.0		−5.2 mA	5.68	5.8	—	5.63	—	5.60	—	
V_{OL}	Low Level Output Voltage	2.0	V_{IH} or V_{IL}	20 μA	—	0	0.1	—	0.1	—	0.1	V
		4.5			—	0	0.1	—	0.1	—	0.1	
		6.0			—	0	0.1	—	0.1	—	0.1	
		4.5		4.0 mA	—	0.17	0.26	—	0.33	—	0.40	
		6.0		5.2 mA	—	0.18	0.26	—	0.33	—	0.40	
I_I	Input Leakage Current	6.0	V_I = V_{CC} or GND		—	—	±0.1	—	±1		±1	μA
I_{CC}	Quiescent Supply Current	6.0	V_I = V_{CC} or GND		—	—	2	—	20		40	μA

AC ELECTRICAL CHARACTERISTICS (V_{CC} = 5V, C_L = 15 pF, T_A = 25°C, Input $t_r = t_f$ = 6ns)

Symbol	Parameter	54HC and 74HC			Unit
		MIN.	TYP.	MAX.	
t_{TLH} t_{THL}	Output Transition Time		4	8	ns
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK-Q, $\overline{Q}$)		18	29	ns
t_{PLH} t_{PHL}	Propagation Delay Time ($\overline{CLR}$, $\overline{PR}$-Q, $\overline{Q}$)		21	33	ns
f_{MAX}	Maximum Clock Frequency	33	63		MHz

AC ELECTRICAL CHARACTERISTICS (C_L = 50pF, Input $t_r = t_f$ = 6ns)

Symbol	Parameter	V_{CC}	Test Condition	T_A = 25°C 54HC and 74HC			−40 to 85°C 74HC		−55 to 125°C 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{TLH} t_{THL}	Output Transition Time	2.0		—	30	75	—	90			ns
		4.5		—	8	15	—	18			
		6.0		—	7	13	—	16			
t_{PLH} t_{PHL}	Propagation Delay Time (CLOK - Q, $\overline{Q}$)	2.0		—	80	165	—	200			ns
		4.5		—	21	33	—	40			
		6.0		—	18	28	—	34			
t_{PLH} t_{PHL}	Progation Delay Time ($\overline{CLR}$, $\overline{PR}$ - Q, $\overline{Q}$)	2.0		—	90	190	—	230			ns
		4.5		—	24	38	—	46			
		6.0		—	21	33	—	40			
f_{MAX}	Maximum Clock Frequency	2.0		6	15	—	5	—			MHz
		4.5		30	57	—	25	—			
		6.0		35	65	—	29	—			
$t_{W(L)}$ $t_{W(H)}$	Minimum Pulse Width (CLOCK)	2.0		—	30	75	—	90			ns
		4.5		—	8	15	—	18			
		6.0		—	7	13	—	16			
$t_{W(L)}$	Minimum Pulse Width ($\overline{CLR}$, $\overline{PR}$)	2.0		—	30	75	—	90			ns
		4.5		—	8	15	—	18			
		6.0		—	7	13	—	16			
t_s	Minimum Set-up Time	2.0		—	35	75	—	90			ns
		4.5		—	8	15	—	18			
		6.0		—	5	13	—	16			
t_h	Minimum Hold Time	2.0		—	—	0	—	0			ns
		4.5		—	—	0	—	0			
		6.0		—	—	0	—	0			
t_{REM}	Minimum Removal Time ($\overline{CLR}$, $\overline{PR}$)	2.0		—	40	100	—	120			ns
		4.5		—	10	20	—	24			
		6.0		—	9	17	—	21			
C_{IN}	Input Capacitance			—	5	10	—	10			pF
C_{PD} (*)	Power Dissipation Capacitance			—	47	—	—	—			pF

Note (*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load.